

Supporting Information

Synthesis of the Smallest Member of the Silylketene Family: $\text{H}_3\text{SiC(H)=C=O}$

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Table S1. Mass-to-charge ratios (m/z) and maximum intensities (I , background noise, integrated from $m/z-0.5$ to $m/z+0.5$) of TPD peaks (between 50 and 300 K and $m/z < 106$) observed by the PI-ReTOF-MS approach (using 9.60 eV photons) upon evaporation of irradiated silane – carbon monoxide ices.

$\text{SiH}_4 - {}^{12}\text{C}^{16}\text{O}$			$\text{SiH}_4 - {}^{12}\text{C}^{18}\text{O}$		
m/z	I	Carrier	m/z	I	Carrier
28	23	${}^{28}\text{Si}^{+a}$	28	18	${}^{28}\text{Si}^{+a}$
29	21	${}^{29}\text{Si}^{+a}$, ${}^{28}\text{SiH}^{+a}$	29	21	${}^{29}\text{Si}^{+a}$
30	13	${}^{30}\text{Si}^{+a}$, ${}^{29}\text{SiH}^{+a}$, ${}^{28}\text{SiH}_2^{+a}$	30	11	${}^{30}\text{Si}^{+a}$, ${}^{28}\text{SiD}^{+a}$
31	4	${}^{30}\text{SiH}^{+a}$, ${}^{29}\text{SiH}_2^{+a}$, ${}^{28}\text{SiH}_3^{+a}$			
45	3	HCO^+ (?)			
72	65	$\text{H}_3{}^{28}\text{Si}(\text{H})\text{CCO}$	74	56	$\text{H}_3{}^{28}\text{Si}(\text{H})\text{CC}^{18}\text{O}$
73	4	$\text{H}_3{}^{29}\text{Si}(\text{H})\text{CCO}$	75	4	$\text{H}_3{}^{29}\text{Si}(\text{H})\text{CC}^{18}\text{O}$
74	2	$\text{H}_3{}^{30}\text{Si}(\text{H})\text{CCO}$	76	2	$\text{H}_3{}^{30}\text{Si}(\text{H})\text{CC}^{18}\text{O}$
92	2	${}^{28}\text{Si}_3\text{H}_8^+$	92	35	
93	11	${}^{28}\text{Si}_2{}^{29}\text{SiH}_8^+$	93	3	
94	2	${}^{28}\text{Si}{}^{29}\text{Si}_2\text{H}_8^+$, ${}^{28}\text{Si}_2{}^{30}\text{SiH}_8^+$	94	2	
102	13	metastable from $\text{Si}_4\text{H}_{10}^{+b}$			
103	2	metastable from $\text{Si}_4\text{H}_{10}^{+b}$			
104	6	metastable from $\text{Si}_4\text{H}_{10}^{+b}$	104	11	metastable from $\text{Si}_4\text{H}_{10}^{+b}$
105	2	metastable from $\text{Si}_4\text{H}_{10}^{+b}$			
$\text{SiH}_4 - {}^{13}\text{C}^{16}\text{O}$			$\text{SiD}_4 - {}^{12}\text{C}^{16}\text{O}$		
m/z	I	Carrier	m/z	I	Carrier
28	21	${}^{28}\text{Si}^{+a}$	28	25	${}^{28}\text{Si}^{+a}$
29	20	${}^{29}\text{Si}^{+a}$, ${}^{28}\text{SiH}^{+a}$	30	31	${}^{30}\text{Si}^{+a}$, ${}^{28}\text{SiD}^{+a}$
30	15	${}^{30}\text{Si}^{+a}$, ${}^{29}\text{SiH}^{+a}$, ${}^{28}\text{SiH}_2^{+a}$	32	17	${}^{30}\text{SiD}^{+a}$, ${}^{28}\text{SiD}_2^{+a}$
31	6	${}^{30}\text{SiH}^{+a}$, ${}^{29}\text{SiH}_2^{+a}$, ${}^{28}\text{SiH}_3^{+a}$	34	3	${}^{29}\text{SiD}_2^{+a}$, ${}^{28}\text{SiD}_3^{+a}$
59	4	?			
74	75	$\text{H}_3{}^{28}\text{Si}(\text{H}){}^{13}\text{C}^{13}\text{CO}$	76	65	$\text{D}_3{}^{28}\text{Si}(\text{D})\text{CCO}$
75	5	$\text{H}_3{}^{29}\text{Si}(\text{H}){}^{13}\text{C}^{13}\text{CO}$	77	5	$\text{D}_3{}^{29}\text{Si}(\text{D})\text{CCO}$
76	5	$\text{H}_3{}^{30}\text{Si}(\text{H}){}^{13}\text{C}^{13}\text{CO}$	78	3	$\text{D}_3{}^{30}\text{Si}(\text{D})\text{CCO}$
92	35	${}^{28}\text{Si}_3\text{H}_8^+$	100	12	${}^{28}\text{Si}_3\text{D}_8^+$
93	5	${}^{28}\text{Si}_2{}^{29}\text{SiH}_8^+$	101	2	${}^{29}\text{Si}_3\text{D}_8^+$
94	2	${}^{28}\text{Si}{}^{29}\text{Si}_2\text{H}_8^+$, ${}^{28}\text{Si}_2{}^{30}\text{SiH}_8^+$			
104	13	metastable from $\text{Si}_4\text{H}_{10}^{+b}$			
105	5	metastable from $\text{Si}_4\text{H}_{10}^{+b}$			

^aFrom multiphoton fragmentation of $\text{Si}(\text{H}/\text{D})_4^+$ ions or $(\text{Si}(\text{H}/\text{D})_4)_n^+$ clusters.

^bMass unresolved peaks due to $\text{Si}(\text{H}/\text{D})_4$ loss in the reflectron region.

Table S2. Cartesian geometries (in Angstrom) of the singlet SiC₂OH₄ isomers (see Fig. 3) and the transition structure (and MSX, see Fig. 5) as obtained at the B3LYP/cc-pVTZ level of theory.

Isomer 1				
C	0.000000	0.058126	0.000000	
Si	0.120335	-1.755364	0.000000	
H	1.547201	-2.158324	0.000000	
H	-0.538649	-2.317390	1.204447	
H	-0.538649	-2.317390	-1.204447	
C	-0.080592	1.263099	0.000000	
O	-0.085172	2.566776	0.000000	
H	-0.989666	2.906640	0.000000	
Isomer 2				
C	0.000000	0.657423	0.000000	
C	-0.077021	1.973934	0.000000	
H	-1.034491	2.479343	0.000000	
H	0.823368	2.568925	0.000000	
O	-1.027589	-0.313487	0.000000	
Si	0.507635	-1.055922	0.000000	
H	0.893537	-1.772800	1.229905	
H	0.893537	-1.772800	-1.229905	
Isomer 3				
C	-0.245603	-0.008883	-0.120248	
Si	1.491528	-0.050327	0.084170	
H	2.191670	1.188447	-0.316060	
H	2.060917	-1.306786	-0.443909	
O	-1.301214	0.823944	0.008329	
C	-1.551308	-0.619847	0.019426	
H	-1.875202	-1.006058	0.977981	
H	-2.067602	-0.990191	-0.858093	
Isomer 4				
C	0.351461	-0.843283	0.000000	
C	1.306700	-1.937959	0.000000	
H	2.318550	-1.512104	0.000000	
H	1.243191	-2.566690	0.894891	
H	1.243191	-2.566690	-0.894891	
O	-1.561078	1.394231	0.000000	
H	-2.265275	0.740185	0.000000	
Si	0.000000	0.817064	0.000000	
Isomer 5				
C	1.280190	1.833824	0.000000	
H	1.701477	2.823254	0.000000	
C	0.082871	-1.113251	0.000000	
H	0.645696	-1.414257	0.888055	
H	0.645696	-1.414257	-0.888055	
O	-1.245752	-1.620418	0.000000	
H	-1.205214	-2.581767	0.000000	
Si	0.000000	0.801924	0.000000	

Isomer 6				
C	1.233047	0.332697	0.000000	
O	2.315394	-0.083936	0.000000	
C	0.000000	0.767154	0.000000	
H	-0.140187	1.840617	0.000000	
Si	-1.447530	-0.400646	0.000000	
H	-2.292698	-0.184812	1.200884	
H	-2.292698	-0.184812	-1.200884	
H	-0.930435	-1.789577	0.000000	
Isomer 7				
C	-0.013895	1.190344	0.029271	
H	-0.048778	1.768227	-0.893526	
H	-0.201283	1.805649	0.906214	
Si	1.142085	-0.330535	0.002861	
H	1.822031	-0.731936	1.253413	
H	1.962889	-0.523017	-1.212364	
C	-0.743009	-0.126590	-0.046181	
O	-1.872829	-0.509244	0.000959	
Isomer 8				
C	0.014460	-1.237638	0.000000	
H	-0.064663	-1.861008	0.892790	
H	-0.064663	-1.861008	-0.892790	
C	1.196576	-0.264711	0.000000	
O	-1.126504	-0.290911	0.000000	
H	-0.368408	2.368942	0.000000	
H	2.243548	-0.499876	0.000000	
Si	0.000000	0.942452	0.000000	
Isomer 9				
H	-1.804817	-2.888201	0.000000	
H	-0.441842	1.528767	1.206383	
H	-0.441842	1.528767	-1.206383	
O	1.637782	0.541949	0.000000	
H	2.208193	1.313040	0.000000	
C	-0.777232	-0.866830	0.000000	
C	-1.326426	-1.939237	0.000000	
Si	0.000000	0.787031	0.000000	
Isomer 10				
Si	-1.385227	-0.278678	0.000000	
H	-2.499479	0.686953	0.000000	
H	-1.388141	-1.121853	1.215076	
H	-1.388141	-1.121853	-1.215076	
O	0.000000	0.695676	0.000000	
H	3.342926	-0.512131	0.000000	
C	1.212160	0.232962	0.000000	
C	2.342176	-0.165467	0.000000	

Isomer 11				
C	-0.938308	0.088239	-0.003583	
C	1.913125	0.657852	0.001299	
H	2.869503	0.197290	-0.241156	
H	1.702409	1.436764	-0.727310	
H	1.992990	1.106455	0.990801	
O	-2.202323	0.312371	-0.106648	
H	-2.627962	0.417989	0.762703	
Si	0.559482	-0.723858	0.005846	

Isomer 12				
Si	0.000000	0.938499	0.000000	
H	-0.145901	1.780300	1.209870	
H	-0.145901	1.780300	-1.209870	
O	-1.095741	-0.400348	0.000000	
C	1.153184	-0.501122	0.000000	
C	0.022472	-1.225799	0.000000	
H	2.172111	-0.841903	0.000000	
H	-0.168318	-2.293369	0.000000	

Isomer 13				
C	0.557222	-1.061174	-0.071883	
H	0.921401	-1.765372	0.671461	
H	0.739018	-1.433112	-1.076739	
Si	-1.122160	-0.046809	0.144063	
C	0.299007	1.081046	-0.102450	
O	1.287041	0.208357	0.077156	
H	-2.001494	-0.052074	-1.069277	
H	0.617612	2.119792	-0.113576	

Isomer 14				
C	0.532954	-0.749817	-0.362738	
C	0.532968	0.749695	-0.362953	
H	1.039769	-1.387529	-1.069710	
H	1.039744	1.387198	-1.070145	
O	1.321610	0.000094	0.588576	
Si	-1.093585	0.000017	0.089079	
H	-2.154098	-0.000153	-0.944550	
H	-1.583627	0.000232	1.482831	

Transition structure (and MSX) in Figure 5

Si	1.55694	1.32867	0.00000	
H	2.47116	0.15629	0.00000	
H	1.76237	2.14816	1.22237	
H	1.76237	2.14816	-1.22237	
H	0.00000	0.80238	0.00000	
C	-1.37006	0.21579	0.00000	
C	-1.32067	-1.12769	0.00000	
O	-1.45609	-2.29811	0.00000	

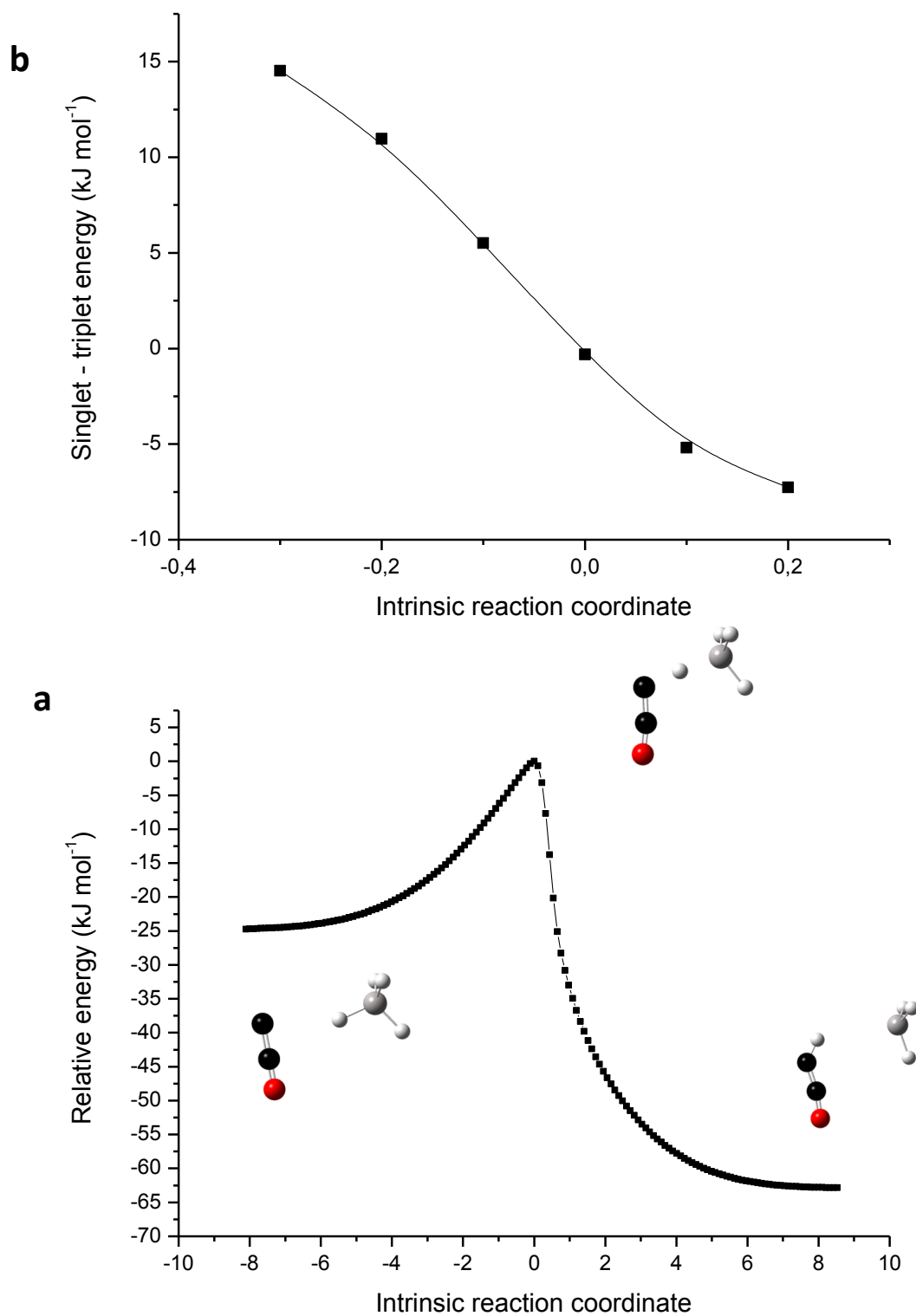


Figure S1. (a) IRC path of the $\text{C}_2\text{O} + \text{SiH}_4 \rightarrow \text{HCCO} + \text{SiH}_3$ reaction on the triplet potential energy surface as obtained at the B3LYP/cc-pVTZ level of theory. (b) Energy difference of the lowest energy singlet and triplet surfaces in the vicinity of the transition structure, along the (B3LYP/cc-pVTZ) IRC path as obtained at the fc CCSD(T)/cc-pVTZ + harmonic B3LYP/cc-pVTZ ZPVE level of theory.